

TECHNICAL DATA SHEET

The PE15A5116 is a high power amplifier that operates from 700 MHz to 2700 MHz and generates 100 watts of saturated output power. The module utilizes GaN and chip-and-wire technology in the manufacturing process that ensures state-of-the-art power performance with excellent power-to-volume ratio that's ideal for broadband jamming, EMC, and test and measurement applications . This Class AB amplifier is designed for a 50 ohm input/output impedance and offers high efficiency and high linearity, operating over a wide dynamic range with impressive typical performance that includes 50 dB of gain, -60 dBc spurious suppression, and -10 dBc harmonics at 60W. The design has input RF power handling capability up to +10 dBm max without damage, and can handle a load VSWR at Pout of 70W of 3.0:1 for all load phase and amplitude conditions under continuous operation. Typical DC bias requirements include +28V and 13A of current at 80W. The module uses an SMA female connectors at the RF input and output ports. The DC interface incorporates a D-Sub 9 pin male connector for DC bias, Enable with TTL logic control, CUrrent sense, and Temperature sense functions. A mating D-Sub socket connector is included. The rugged amplifier design operates over a wide temperature range from -20°C to +60°C, and can withstand relative humidity exposure up to 95% maximum. An available heatsink with cooling fan (model PE15G5068F) is recommended to maintain an optimum baseplate temperature during operation.

Features

- GaN High Power Amplifier Design
- 700 MHz to 2700 MHz Frequency Range
- · Psat 100 Watts typ
- Gain: 50 dB typ
- Gain Flatness +/- 2 dB
- Spurious Supression -60 dBc
- DC Bias +28VDC @ 13A Current
- Max RF input Power +10 dBm
- Enable with TTL Logic Control
- · Current Sense and Temperature Sense features

Applications

• EMC

- Military Radio
- Communication Systems

Broadband Jamming

 Multioctave High Gain Power Amplifier

- 50 Ohms Input and Output Matched
- Instantaneous Broadband
- Built-In control and protection circuits
- Class AB
- SMA Female Input/Output Connectors
- D-Sub Control Connector with Mating Female Connector
- Operational Temperature -20°C to +60°C
- Optional Heatsink Available: Model PE15G5068F
 - Band Specific High Power Linear Applications in P/L/S Frequency bands
 - · Test and Measurement

Electrical Specifications (TA = +25°C, DC Voltage = +28Volts, DC Current = 13A)

Description	Minimum	Typical	Maximum	Units
Frequency Range	0.7		2.7	GHz
Small Signal Gain		50		dB
Gain Flatness		±2		dB
Pout at Sat.	+60	+100		dBm
Harmonics @60 Watts		-10	-8	dBc
Spurious		-60		dBc
Impedance (Input)		50		Ohms
Impedance (Output)		50		Ohms
Input Return Loss			-10	dB

Click the following link (or enter part number in "SEARCH" on website) to obtain additional part information including price, inventory and certifications: 50 dB Gain, 100 Watt Psat, 0.7 GHz to 2.7 GHz, High Power GaN Amplifier, Class AB, SMA PE15A5116

Pasternack Enterprises, Inc. • P.O. Box 16759, Irvine, CA 92623 Phone: (866) 727-8376 or (949) 261-1920 • Fax: (949) 261-7451

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+24	+28	+32	Volts
	13		A
	2	5	μs
-20		+60	°C
-	+24 -20	13 2	13 2 5

*@Pout=80W **@ 1 kHz TTL Electrical Specification Notes: Allow for 20% Increased DC Current during initial power-up stage

Absolute Maximum Rating

Parameter	Rating	
Input RF drive level without damage Load VSWR @ Pout =70W	+10 dBm (Max) ∞ @ all load phase & amplitude for duration of 1 minute; 3:1 @ all load phase & amplitude continuous	
Over Temperature	85°C @ heatsink [restored @ 60°C]	
lechanical Specifications		
Size Length Width Height Weight Input Connector Output Connector Bias Connector Cooling	7.08 in [179.83 mm] 3.54 in [89.92 mm] 0.98 in [24.89 mm] 2 lbs [907.18 g] SMA Female SMA Female 9-Pin D-Subminiature Male Baseplate Conduction	
Temperature Operating Range Storage Range Humidity	-20 to +60 deg C -30 to +75 deg C 95%	

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Compliance Certifications (see product page for current document)

Plotted and Other Data

Notes: • Values at +25 °C, sea level

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Amplifier Power-up Precautions Confirm that proper ESD precautions and controls are always in place before handling any Amplifier module. 1.) 2.) fan may also be used. Damage caused from overheating will void the warranty. 3.) properly. 4.) 5.) Confirm the system is designed and calibrated for 50 ohms. Any impedance mismatch may cause performance issues. 6.) 7.) Use a fixed attenuator between the signal source and input port of the Amplifier to optimize the input VSWR match. 8.) 9.) Amplifier datasheet). Pin for Small Signal Gain = P1dB-SSG-10 dB P_{in} for P1dB = P1dB-SSG+1 dB 10.) Confirm the Network Analyzer is always connected to the Amplifier first before DC power is applied to the Amplifier. powered up with DC voltage. Amplifier and void the warranty. 13.) will likely damage the Amplifier and void the warranty. 14.) frequency band of the amplifier. PE15A5116

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- Confirm adequate thermal management is in place to effectively dissipate heat away from the Amplifier package. The Amplifier operational baseplate temperature must be within the operational temperature range stated in the Amplifier datasheet. Depending on the design and thermal requirements, using a heatsink with cooling fan is always recommended for safe reliable operation. A heat sink without a cooling
- Confirm adequate system grounding is established. The DC power supply and Amplifier must have a common ground in order to operate
- Power Amplifiers may require additional DC Current when initially powered-up. Depending on the design, the input current draw could range from an additional 10% to 100% above the maximum rated DC current of the Amplifier. This varies based on product part number.
- Confirm the DC power supply, if limited, is set to allow for additional start-up current that's rated for the Power Amplifier.
- Perform a CALIBRATION (if required) with the loads before connecting the Amplifier to the Network Analyzer to ensure proper performance.
- Confirm the input power level at the input port of the amplifier does not exceed the maximum rated limit for input power (as stated in the
- 11.) As long as the input and output ports of the amplifier are connected to a 500hm load and RF signal power is applied, the Amplifier can be
- 12.) Confirm the Amplifier output load is matched for a 50 Ohm impedance and will not exceed the maximum rated VSWR or Return Loss limit for the Amplifier. Exceeding the maximum rated VSWR or Return Loss limit will result in reflected signal power that could damage the
- Power Amplifier connected to an Antenna for signal transmission It's strongly recommended to use a high power fixed attenuator pad or an Isolator between the output port of the Amplifier and input port to the antenna. Any reflected signal power due to impedance mismatch
- The attenuator or isolator used at the output port of the Amplifier must be rated to handle the output power level and operational

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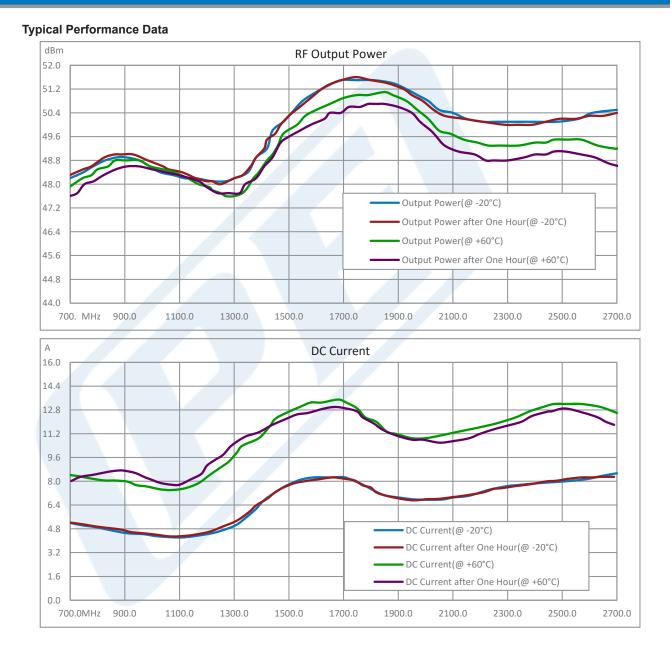
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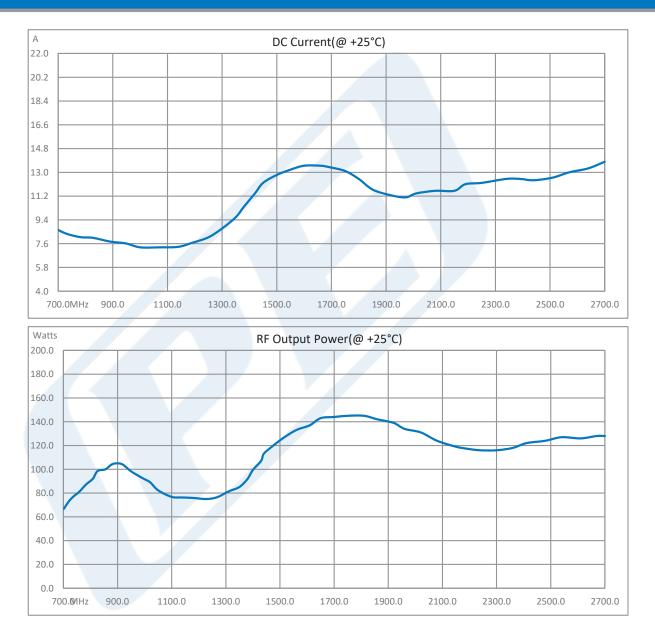
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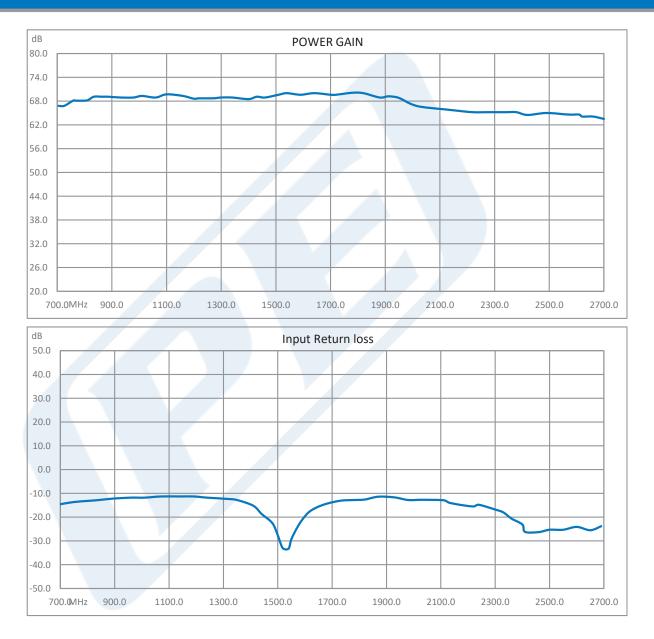
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50 dB Gain, 100 Watt Psat, 0.7 GHz to 2.7 GHz, High Power GaN Amplifier, Class AB, SMA from Pasternack Enterprises has same day shipment for domestic and International orders. Our RF, microwave and millimeter wave products maintain a 99.4% availability and are part of the broadest selection in the industry.

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URL: https://www.pasternack.com/50-db-gain-2.7-ghz-high-power-high-gain-amplifier-sma-pe15a5116-p.aspx

The information contained in this document is accurate to the best of our knowledge and representative of the part described herein. It may be necessary to make modifications to the part and/or the documentation of the part, in order to implement improvements. Pasternack reserves the right to make such changes as required. Unless otherwise stated, all specifications are nominal. Pasternack does not make any representation or warranty regarding the suitability of the part described herein for any particular purpose, and Pasternack does not assume any liability arising out of the use of any part or documentation.

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PE15A5116

PE15A5116 CAD Drawing

50 dB Gain, 100 Watt Psat, 0.7 GHz to 2.7 GHz, High

Power GaN Amplifier, Class AB, SMA

